

Features

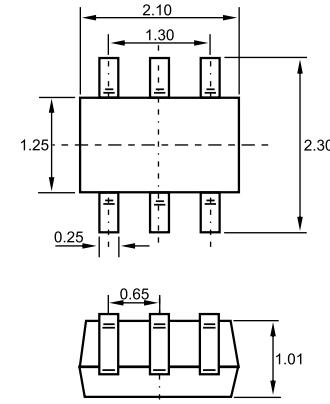
- ❖ Complementary Pair
- ❖ One 3904-Type NPN,
One 3906-Type PNP
- ❖ Epitaxial Planar Die Construction
- ❖ Ideal for Low Power Amplification and Switching

MAKING: K46 •

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	5	V
I_c	Collector Current -Continuous	0.2	A
P_c	Collector Power Dissipation	0.2	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55-150	$^\circ\text{C}$

SOT-363



Dimensions in inches and (millimeters)

NPN 3904 ELECTRICAL CHARACTERISTICS ($T_{\text{amb}}=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	$I_C = 10\mu\text{A}, I_E = 0$	60		V
Collector-emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	$I_C = 1\text{mA}, I_B = 0$	40		V
Emitter-base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	$I_E = 10\mu\text{A}, I_C = 0$	5		V
Collector cut-off current	I_{CBO}	$V_{\text{CB}} = 30\text{ V}, I_E = 0$		0.05	μA
Collector cut-off current	I_{CEO}	$V_{\text{CE}} = 30\text{ V}, I_B = 0$		0.5	μA
Emitter cut-off current	I_{EBO}	$V_{\text{EB}} = 5\text{ V}, I_C = 0$		0.05	μA
DC current gain	$h_{\text{FE}(1)}$	$V_{\text{CE}} = 1\text{V}, I_C = 0.1\text{mA}$	40		
	$h_{\text{FE}(2)}$	$V_{\text{CE}} = 1\text{V}, I_C = 1\text{mA}$	70		
	$h_{\text{FE}(3)}$	$V_{\text{CE}} = 1\text{V}, I_C = 10\text{mA}$	100	300	
	$h_{\text{FE}(4)}$	$V_{\text{CE}} = 1\text{V}, I_C = 50\text{mA}$	60		
	$h_{\text{FE}(5)}$	$V_{\text{CE}} = 1\text{V}, I_C = 100\text{mA}$	30		
Collector-emitter saturation voltage	$V_{\text{CE}(\text{sat}1)}$	$I_C = 10\text{ mA}, I_B = 1\text{mA}$		0.2	V
	$V_{\text{CE}(\text{sat}2)}$	$I_C = 50\text{ mA}, I_B = 5\text{mA}$		0.3	V
Base-emitter saturation voltage	$V_{\text{BE}(\text{sat}1)}$	$I_C = 10\text{ mA}, I_B = 1\text{mA}$	0.65	0.85	V
	$V_{\text{BE}(\text{sat}2)}$	$I_C = 50\text{ mA}, I_B = 5\text{mA}$		0.95	V
Transition frequency	f_T	$V_{\text{CE}} = 20\text{V}, I_C = 20\text{mA}, f = 100\text{MHz}$	300		MHz
Noise figure	NF	$V_{\text{CE}} = 5\text{V}, I_C = 0.1\text{mA}, f = 1\text{KHz}, R_g = 1\text{K}\Omega$		5	dB
Output Capacitance	C_{ob}	$V_{\text{CB}} = 5\text{V}, I_E = 0, f = 1\text{MHz}$		4	pF
Delay time	t_d	$V_{\text{CC}} = 3\text{V}, V_{\text{BE}} = 0.5\text{V}$		35	nS
Rise time	t_r	$I_C = 10\text{mA}, I_{B1} = -I_{B2} = 1\text{mA}$		35	nS
Storage time	t_s	$V_{\text{CC}} = 3\text{V}, I_C = 10\text{mA}$		200	nS
Fall time	t_f	$I_{B1} = -I_{B2} = 1\text{mA}$		50	nS

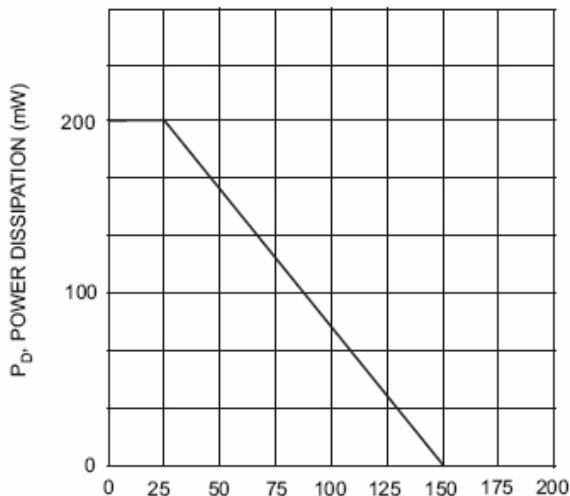
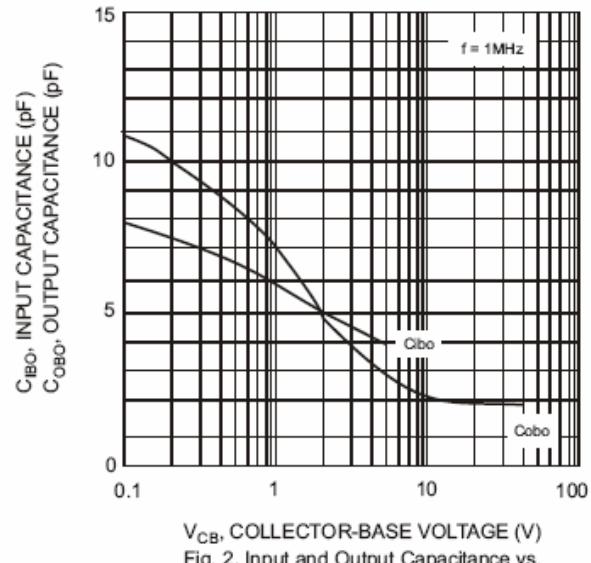
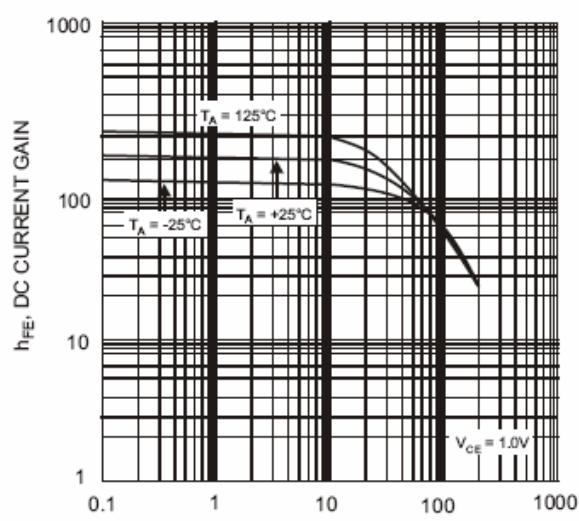
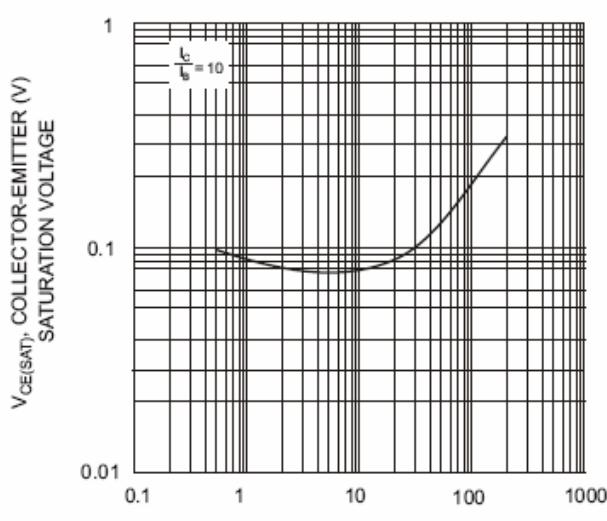
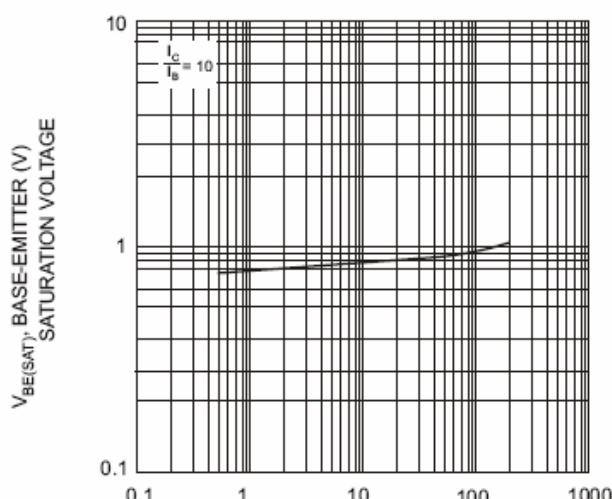
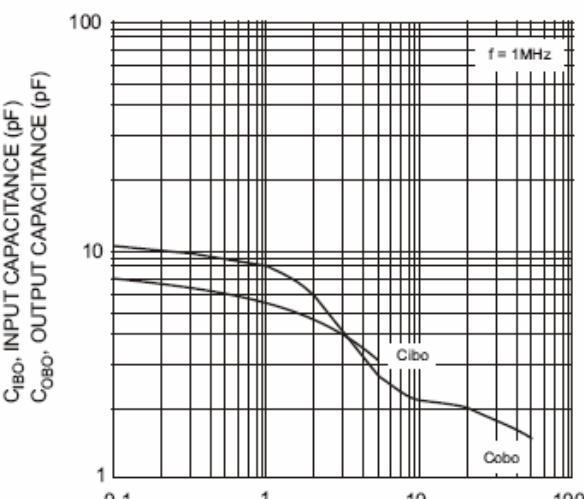
**MAXIMUM RATINGS(T_A=25°C unless otherwise noted)**

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	-40	V
V _{CEO}	Collector-Emitter Voltage	-40	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _c	Collector Current -Continuous	-0.2	A
P _c	Collector Power Dissipation	0.2	W
T _J	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55-150	°C

PNP 3906 ELECTRICAL CHARACTERISTICS (T_{amb}=25°C unless otherwise specified)

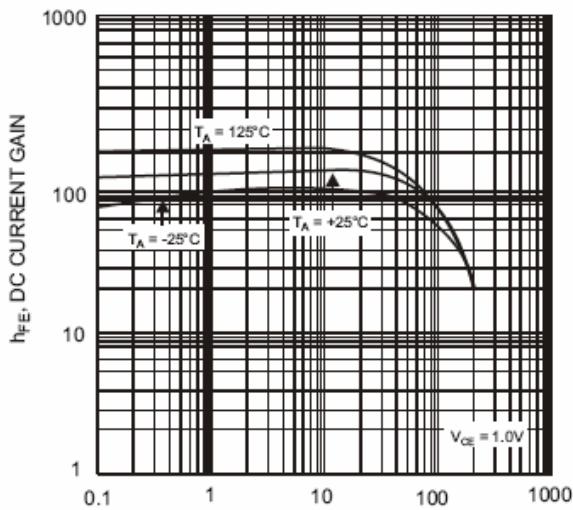
Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-10μA,I _E =0	-40			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-1mA,I _B =0	-40			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-10μA,I _C =0	-5			V
Collector cut-off current	I _{CBO}	V _{CB} =-30V,I _E =0			-0.05	μA
Emitter cut-off current	I _{EBO}	V _{EB} =-5V,I _C =0			-0.05	μA
DC current gain	h _{FE(1)}	V _{CE} =-1V,I _C =-0.1mA	60			
	h _{FE(2)}	V _{CE} =-1V,I _C =-1mA	80			
	h _{FE(3)}	V _{CE} =-1V,I _C =-10mA	100		300	
	h _{FE(4)}	V _{CE} =-1V,I _C =-50mA	60			
	h _{FE(5)}	V _{CE} =-1V,I _C =-100mA	30			
Collector-emitter saturation voltage	V _{CE(sat)1}	I _C =-10mA,I _B =-1mA			-0.25	V
	V _{CE(sat)2}	I _C =-50mA,I _B =-5mA			-0.4	V
Base-emitter saturation voltage	V _{BE(sat)1}	I _C =-10mA,I _B =-1mA	-0.65		-0.85	V
	V _{BE(sat)2}	I _C =-50mA,I _B =-5mA			-0.95	V
Transition frequency	f _T	V _{CE} =-20V,I _C =-10mA,f=100MHz	250			MHz
Collector output capacitance	C _{ob}	V _{CB} =-5V,I _E =0,f=1MHz			4.5	pF
Noise figure	NF	V _{CE} =-5V,I _C =-0.1mA,f=1KHZ,R _g =1KΩ			4	dB
Delay time	t _d	V _{CC} =-3V,V _{BE} =-0.5V			35	nS
Rise time	t _r	I _C =-10mA,I _{B1} =-I _{B2} =-1mA			35	nS
Storage time	t _s	V _{CC} =-3V,I _C =-10mA			225	nS
Fall time	t _f	I _{B1} =-I _{B2} =-1mA			75	nS

Typical Characteristics

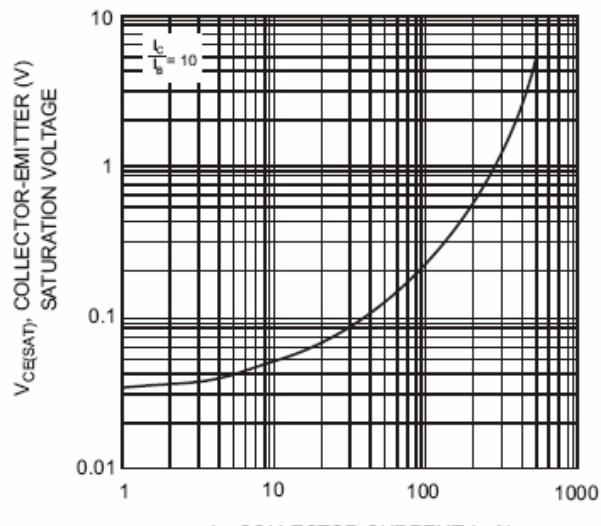
 T_A , AMBIENT TEMPERATURE (°C)Fig. 1, Max Power Dissipation vs
Ambient Temperature (Total Device) V_{CB} , COLLECTOR-BASE VOLTAGE (V)Fig. 2, Input and Output Capacitance vs.
Collector-Base Voltage (NPN-3904) I_C , COLLECTOR CURRENT (mA)Fig. 3, Typical DC Current Gain vs
Collector Current (NPN-3904) I_C , COLLECTOR CURRENT (mA)Fig. 4, Typical Collector-Emitter
Saturation Voltage vs. Collector Current (NPN-3904) I_C , COLLECTOR CURRENT (mA)Fig. 5, Typical Base-Emitter
Saturation Voltage vs. Collector Current (NPN-3904) V_{CB} , COLLECTOR-BASE VOLTAGE (V)Fig. 6, Input and Output Capacitance vs.
Collector-Base Voltage (PNP-3906)

MMDT3946

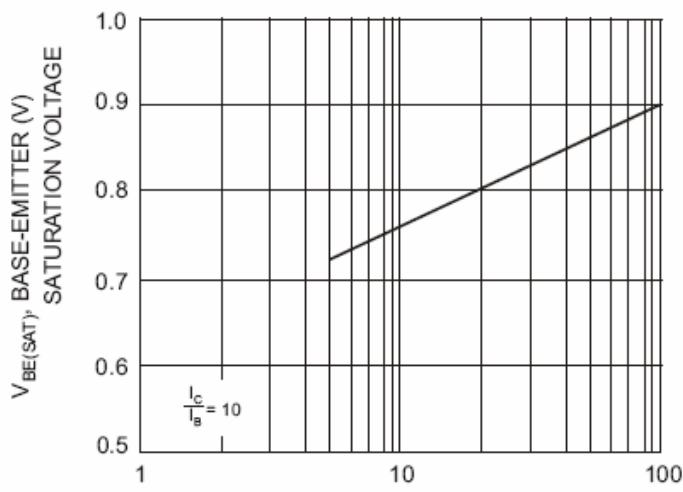
Complementary NPN/PNP Transistor



I_C , COLLECTOR CURRENT (mA)
Fig. 7, Typical DC Current Gain vs
Collector Current (PNP-3906)



I_C , COLLECTOR CURRENT (mA)
Fig. 8, Typical Collector-Emitter Saturation Voltage
vs. Collector Current (PNP-3906)



I_C , COLLECTOR CURRENT (mA)
Fig. 9, Typical Base-Emitter
Saturation Voltage vs. Collector Current (PNP-3906)

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